# NSN 5961-01-079-9112

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### **Inclosure Material:**

Metal

# **Overall Length:**

Between 0.250 inches and 0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

# **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

450.0 collector to base voltage/static/emitter open and 350.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current

# Power Rating Per Characteristic:

6.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

1 case and 2 pin

### **Specification Data:**

81349-mil-s-19500/510 government specification

# Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

No